

Features

- Operates DC - 4 GHz on Single Supply
- ASIC TTL / CMOS Driver
- Low DC Power Consumption
- 50 Ohm Nominal Impedance
- Test Boards are Available
- Tape and Reel are Available
- Lead-Free 4 x 6 mm PQFN Package
- 100% Matte Tin Plating over Copper
- Halogen-Free "Green" Mold Compound
- 260°C Reflow Compatible
- RoHS* Compliant Version of SW90-0001

Description

M/A-COM's MASW-007070-000100 is a SPST absorptive pHEMT switch with integral TTL driver. This device is in an MLP plastic surface mount package. This switch offers excellent broadband performance and repeatability from DC to 4 GHz, while maintaining low DC power dissipation. The MASW-007070-000100 is ideally suited for wireless infrastructure applications.

Ordering Information

Part Number	Package
MASW-007070-000100	Bulk Packaging
MASW-007070-0001TR	1000 piece reel
MASW-007070-0001TB	Sample Test Board

Note: Reference Application Note M513 for reel size information.

Pin Configuration^{1,2,3,4}

Pin No.	Function	Pin No.	Function
1	NC	17	NC
2	NC	18	NC
3	C1	19	V _{CC}
4	NC	20	NC
5	NC	21	CP2
6	NC	22	NC
7	NC	23	CP1
8	NC	24	NC
9	NC	25	V _{EE}
10	NC	26	GND
11	GND	27	RF1
12	RF2	28	GND
13	GND	29	NC
14	NC	30	V _{EE}
15	NC	31	NC
16	NC	32	V _{CC}

1. NC = No Connection
2. VEE is internally generated and must remain isolated from external power supplies. Generated noise is typical of switching DC-DC Converters
3. Connections and external components shown in functional schematic are required. 0.1 μF Capacitors need to be located near pins 30 & 32.
4. The exposed pad centered on the package bottom must be connected to RF and DC ground. (For PQFN Packages)

Truth Table (Switch)

Control Input	Condition of the Switch
C1	RF1 to RF2
0	Off
1	On

* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

Electrical Specifications: $T_A = 25^\circ\text{C}$, $Z_0 = 50\Omega$

Parameter	Test Conditions	Frequency	Units	Min	Typ	Max
Insertion Loss	RF1—RF2 (All Logic "1")	DC - 4.0 GHz	dB	—	—	0.85
Isolation	RF1—RF2 (All Logic "0")	DC - 4.0 GHz	dB	25	—	—
VSWR	On (RF1, RF2) (All Logic "1")	DC - 4.0 GHz	Ratio	—	—	1.5:1
VSWR	Off (RF1, RF2) (All Logic "0")	DC - 4.0 GHz	Ratio	—	—	1.5:1
1 dB Compression	— —	50 MHz	dBm	—	24	—
		0.5 - 4.0 GHz	dBm	—	30	—
Input IP_3	Two-tone inputs up to +5 dBm	50 MHz	dBm	—	40	—
		0.5-4.0 GHz	dBm	—	48	—
Switching Speed	Ton (50% Control to 10% RF)	—	ns	—	32	—
	Toff (50% Control to 90% RF)	—	ns	—	20	—
	Trise (10% to 90% RF)	—	ns	—	7	—
	Tfall (90% to 10% RF)	—	ns	—	2	—
V_{CC}	—	—	V	4.5	5.0	5.5
V_{IL} V_{IH}	LOW-level input voltage	—	V	0.0	—	0.8
	HIGH-level input voltage	—	V	2.0	—	5.0
I_{in} (Input Leakage Current)	$V_{in} = V_{CC}$ or GND	—	μA	-1.0	—	1.0
I_{CC}^5	V_{CC} min to max, Logic "0" or "1"	—	mA	—	5	8
Turn-on Current ⁶	For guaranteed start-up	—	mA	—	—	125
ΔI_{CC} (Additional Supply Current Per TTL Input Pin)	$V_{CC} = \text{Max}$, $V_{cntrl} = V_{CC} - 2.1 \text{ V}$	—	mA	—	—	1.0
Switching Noise	Generated from DC-DC Converter with recommended capacitors	3.5 MHz	dBm	—	-93	—
Thermal Resistance θ_{jc}	—	—	$^\circ\text{C/W}$	—	15	—

- During turn-on, the device requires an initial start up current (I_{CC}) specified as "Turn-on Current". Once operational, I_{CC} will drop to the specified levels.
- The DC-DC converter is guaranteed to start in 100 μs as long as the power supplies have the maximum turn-on current available for start up.

Absolute Maximum Ratings ^{7,8}

Parameter	Absolute Maximum
Max. Input Power 0.05 GHz 0.5 - 4.0 GHz ⁹	+27 dBm +34 dBm
V _{CC}	-0.5V ≤ V _{CC} ≤ +6.0V
V _{in} ¹⁰	-0.5V ≤ V _{in} ≤ V _{CC} + 0.5V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +125°C

7. Exceeding any one or combination of these limits may cause permanent damage to this device.
8. M/A-COM does not recommend sustained operation near these survivability limits.
9. When the RF input is applied to the terminated port, the absolute maximum power is +30 dBm.
10. Standard CMOS TTL interface, latch-up will occur if logic signal is applied prior to power supply.

Handling Procedures

Please observe the following precautions to avoid damage:

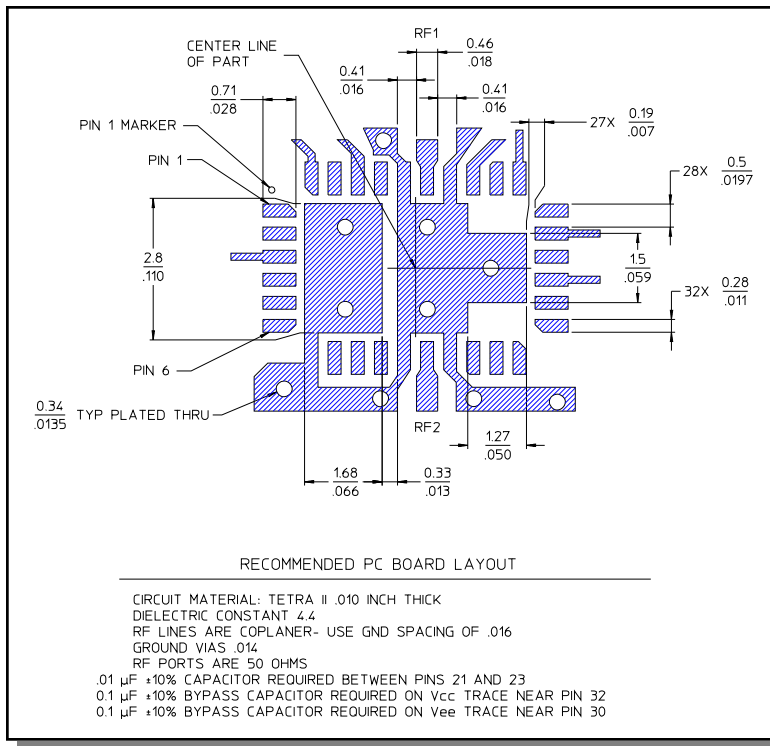
Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Moisture Sensitivity

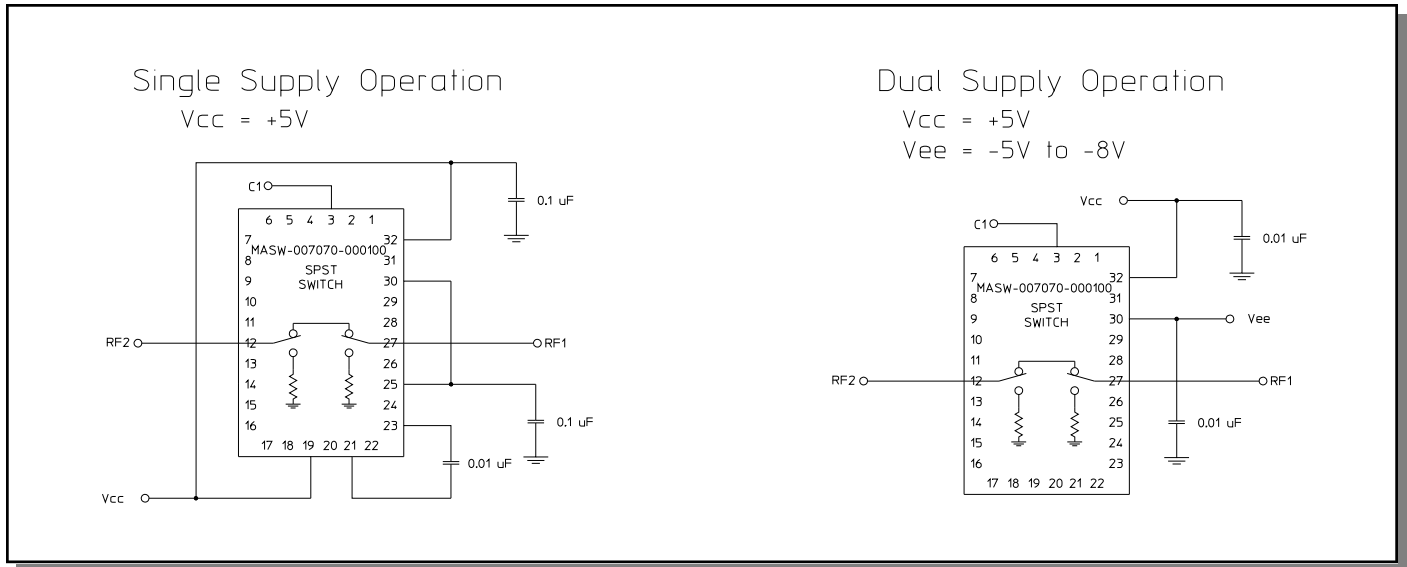
The MSL rating for this part is defined as Level 2 per IPC/JEDEC J-STD-020. Parts shall be stored and/or baked as required for MSL Level 2 parts.

Recommended PCB Configuration¹¹



11. Application Note C2083 is available on line at www.macomtech.com

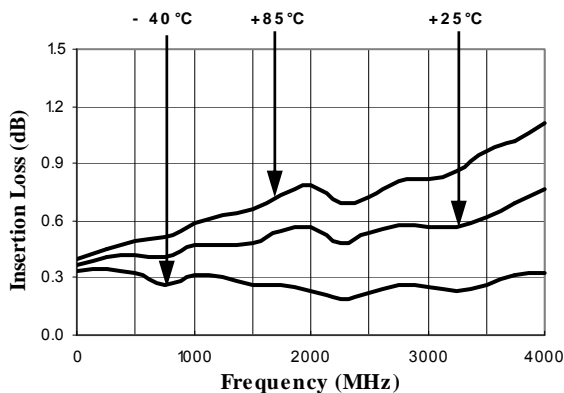
Functional Schematic¹²



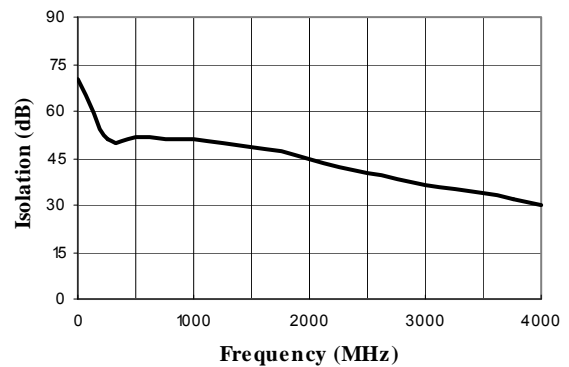
¹²Dual Supply Operation will eliminate the start-up current mentioned in Note 5. It will also eliminate spurious signals caused by the DC-DC converter that are present in single supply operation.

Typical Performance Curves

Insertion Loss vs. Frequency

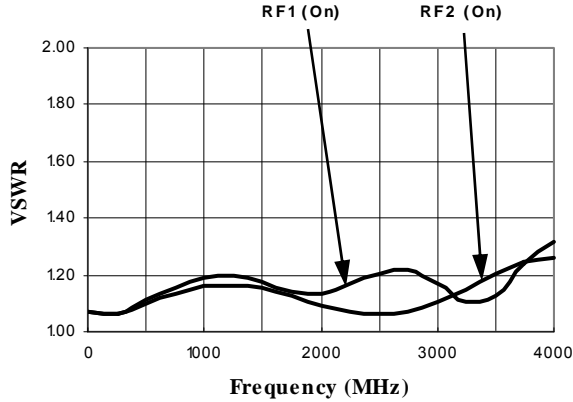


Isolation (dB) vs. Frequency

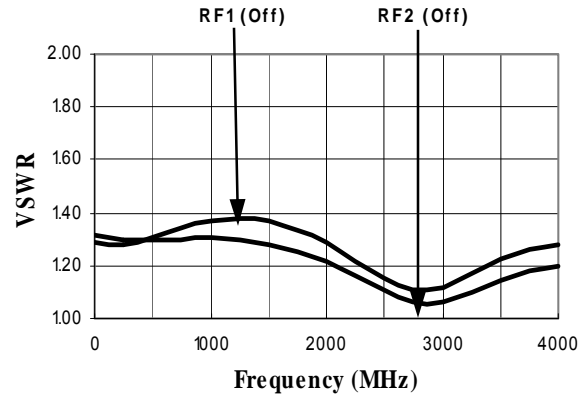


Typical Performance Curves

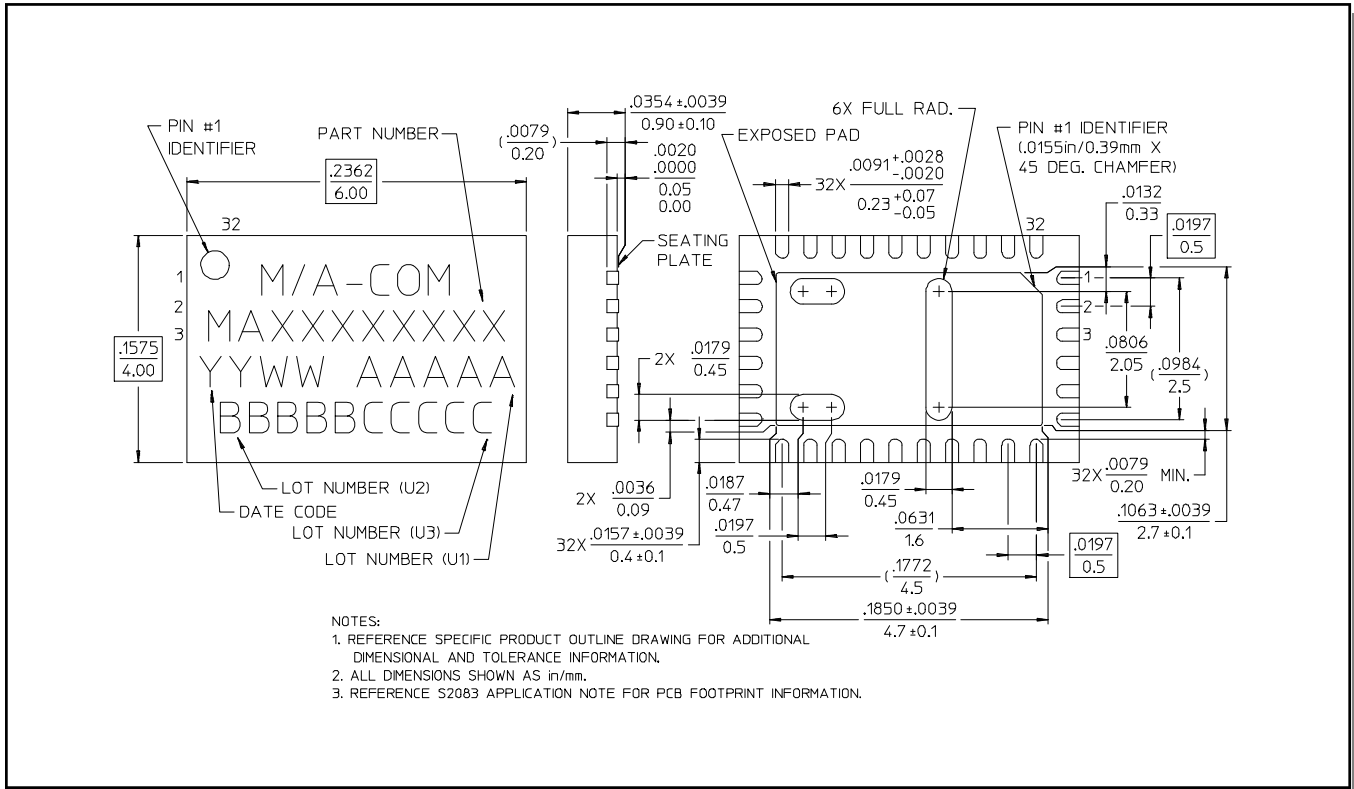
On VSWR vs. Frequency



VSWR (Terminations) vs. Frequency



CSP-1, Lead-Free 4 x 6 mm, 32-lead PQFN†



† Reference Application Note M538 for lead-free solder reflow recommendations.